

16-string, White and RGB LED Drivers with Adaptive Configuration, EEPROM, and SPI/I²C/SMBus Serial Interface

Datasheet Brief



General Description

The Atmel® LED Drivers-MSL2160 and MSL2161 compact, high-power LED string drivers use external current control MOSFETs to sink up to 350mA per string, with current accuracy and matching better than 1.5%. The MSL2160/1 drive 16 parallel strings of LEDs, and offer fault detection and management of open and short circuit LEDs.

Atmel LED Drivers-MSL2160/MSL2161

16-string, White and RGB LED Drivers with Adaptive Configuration, EEPROM, and SPI/I²C/SMBus Serial Interface

The MSL2160 features a 20MHz SPI bus, and the MSL2161 offers a 1MHz I^2C serial interface. Both interfaces support video frame-by-frame LED string intensity control for up to eight interconnected devices, allowing active area dimming and phase shifted PWM dimming for improved performance. Both devices include an advanced PWM engine that synchronizes PWM dimming to the video signal for reduced motion blur and waterfall noise.

The MSL2160/1 adaptively controls the DC-DC converters that power the LED strings using Atmel's Adaptive SourcePower™ technology. This scheme optimizes power consumption without sacrificing LED current accuracy. Peak LED string currents are set using current sense resistors, and global string current is adjustable with 8-bit control. Global string drive pulse width is adjusted with an 8-bit global intensity register, and individual string pulse width is modulated with 12-bit control.

The MSL2160/1 monitors the LED strings for open circuit, short circuit, loss-of-sync, and over-temperature faults, and provide a hardware fault output to notify the MCU. Detailed fault status and control are available through the serial interface. Additionally, the MSL2160/1 includes an on-chip EEPROM that allows the power-up defaults to be customized via the serial interface.

The MSL2160/1 are offered in 9 x 9 x 0.85mm, 64-pin TQFN packages and operate over a -40° C to $+105^{\circ}$ C temperature range.

Applications

Long Life, Efficient LED Backlighting for:

- Televisions and Desktop Monitors
- Medical and Industrial Instrumentation
- Automotive Audio-visual Displays

Channel Signs

Architectural Lighting

Ordering Information

16-CHANNEL LED STRING DRIVERS				
PART INTERFACE PACKAGE				
MSL2160DQ	SPI	64-pin, 9 x 9 x 0.85mm TQFN		
MSL2161DQ	I ² C	64-pin, 9 x 9 x 0.85mm TQFN		

16-string, White and RGB LED Drivers with Adaptive Configuration, EEPROM, and SPI/I²C/SMBus Serial Interface

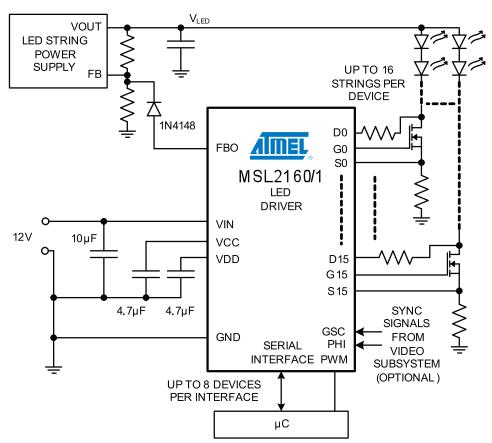
Key Features

- 12-bit PWM String Dimming
- Fast Serial Interfaces Support up to 8 Devices per Bus:
 - MSL2161 1MHz I²C
 - MSL2160 20MHz SPI
- 8-bit Adaptive Power Correction Maximizes
 Efficiency of up to Three String Power Supplies
- External MOSFETs for High Voltage and/or Current
- Drives up to 16 Parallel LED Strings per Device
- Supports Adaptive, Real-time Area Dimming for Highest Dynamic Range in LCD TVs and Monitors
- Programmable String Phase Reduces Motion Blur and Improves Efficiency

- Global Intensity Control via Serial Interface
- ±1.5% Current Accuracy and Current Balance
- Flexible Video Frame (VSYNC) and Line (HSYNC)
 Sync Include Frequency Multipliers and Dividers
- Second Set of PWM Registers Select Alternate Brightness and Timing with Single Control
- EEPROM Saves Power-on Default Settings
- LED Open Circuit and Short Circuit Fault Detection
- Individual Fault Detection Enable for Each String
- Over-temperature Shut-off Protection
- Broadcast Write Simplifies Configuration
- -40°C To +105°C Operating Temperature Range

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Application Circuit





Atmel LED Drivers-MSL2160/61 Overview

The MSL2160/1 LED string controllers drive, monitor, and dim multiple LEDs at high efficiency for LCD backlighting and signage applications. This section summarizes the capabilities of the MSL2160/1 for quick evaluation.

How Many LEDs and Drivers?

The MSL2160/1 controls 16 strings of seriesconnected LEDs at up to 350mA per string. Up to eight MSL2160/1s share a serial interface. The maximum number of LEDs per string is determined by the maximum power supply voltage, the LED forward voltage drop ($V_{\rm F}$), and the gate drive outputs of the MSL2160/1. The MSL2160/1 FET gate drive outputs are optimized for FETs requiring up to 10nC of charge.

LEDs, String Power Supplies and Efficiency Optimizers (EOs)

The MSL2160/1 Efficiency Optimizer (EO) circuits dynamically adjust up to three LED string power supplies to the minimum voltage necessary to accurately drive the LED strings while assuring accurate current flow. The power supplies can use any topology, and are typically DC-DC boost or buck, or AC-DC off-line switcher supplies.

The MSL2160/1 allows RGB LEDs to be driven by three separate string supplies, and feature three independent EO outputs to maximize the efficiency for each supply. Although not required, it is wise to use this capability even for single-color systems, such as white backlighting LEDs in an LCD monitor or TV application.

Timing, PWM, Intensity Controls and Synchronization

For video applications, the PWM LED drive signals synchronize to the LCD's video frame timing via the PHI input, and to the LCD's pixel timing via the GSC input. This synchronization eliminates beating artifacts. Suitability for LED backlight architectures is shown in Table 1. Area LED dimming for direct backlighting is supported for contrast and color gamut improvement. Motion blur is reduced by setting each LED string's PWM phasing individually to synchronize PWM off times with the LCD timing.

The MSL2160/1 also includes easily controlled internal PWM timing generation for stand alone (non-video) LED lighting applications that do not provide external timing sources. One MSL2160/1 simply generates PWM timing for itself and for the other devices in a multiple-device application. Optionally, a single external PWM signal applied to the PWM input controls all of the strings' on times, with automatic progressive phase delay available through a single control bit.

Table 1. LED Common Backlight Drive Architectures and Features

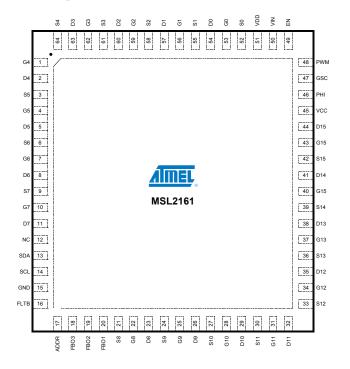
BACKLIGHT TYPE	MOTION BLUR REMOVAL	AREA DIMMING MANAGEMENT	STRING SUPPLY OPTIONS	
White LED - bottom edge-lit	No	No		
White LED - top/bottom edge-lit	No	No	Up to three efficiency	
White LED - four sides edge-lit	No	No	optimized power supplies	
White LED - direct back-lit	Yes, LED string phasing	Higher contrast ratio (area dimming)		
RGB LED - direct back-lit	Yes, LED string phasing	Higher contrast ratio and color gamut	Three efficiency optimized power supplies	

16-string, White and RGB LED Drivers with Adaptive Configuration, EEPROM, and SPI/I²C/SMBus Serial Interface

Table 2. Timing and LED Intensity Control Capability

LED INTENSITY CONTROL	RESOLUTION
Global LED string current adjust	8-bits DAC reduces string current globally from maximum set by global resistor
Global LED string PWM	8-bit global PWM control
Individual LED string PWM	12-bit PWM individual string control
Total LED string PWM control	12-bit LED string PWMs, computed from global and individual PWM settings

Package Pin-out



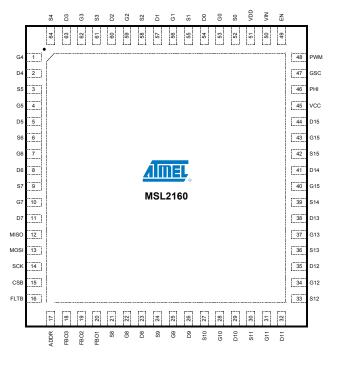
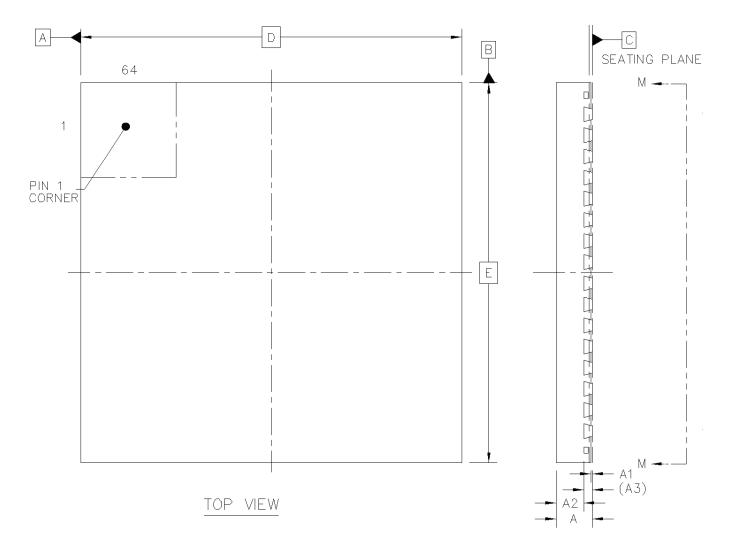


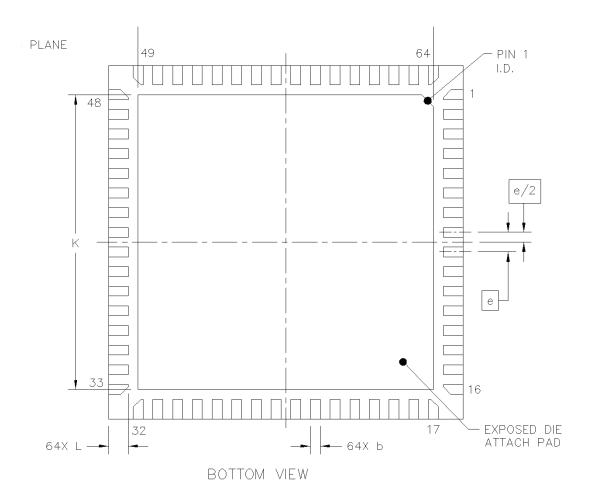
Figure 1. Atmel LED Driver-MSL2161 Pin-out, 64-pin TQFN.

Figure 2. Atmel LED Driver-MSL2160 Pin-out, 64-pin TQFN.



Figure 3. Package Dimensions: 64-pin, 9mm x 9mm x 0.85mm TQFN (0.5mm pin pitch) with Exposed Pad.





	SYMBOL	MIN	NOM	MAX		
TOTAL THICKNESS	А	0.8 0.85 0.9				
STAND OFF		A1	0 0.035 0.0		0.05	
MOLD THICKNESS		A2		0.65	0.67	
L/F THICKNESS	А3	0.203 REF				
LEAD WIDTH	b	0.2	0.25	0.3		
BODY SIZE	Х	D	9 BSC			
IBODI SIZE	Y	E	9 BSC			
LEAD PITCH		е	0.5 BSC			
EP SIZE	Х	J	7.4	7.5	7.6	
EP SIZE 	Y	K	7.4	7.5	7.6	
LEAD LENGTH		L	0.45	0.5	0.55	



Package Pin Descriptions

Table 3. Pin Assignments

	PIN N	IAME	
PIN	MSL2161	MSL2160	PIN DESCRIPTION
1	G4	G4	Gate output 4 Gate drive output for external MOSFET 4. Connect G4 to the gate of the external MOSFET driving LED string 4. If unused, leave G4 unconnected.
2	D4	D4	Drain sense input 4 Drain sense input for external MOSFET 4. Connect D4 through a $10M\Omega$ resistor to the drain of the external MOSFET driving LED string 4. If unused, connect D4 to ground.
3	S5	S5	Source sense input 5 Source sense input for external MOSFET 5. Connect S5 to the source of the external MOSFET and to the current sense resistor for LED string 5. The full-scale LED current threshold is reached when 500mV is across the current sense resistor. If unused, connect S5 to ground.
4	G5	G5	Gate output 5 Gate drive output for external MOSFET 5. Connect G5 to the gate of the external MOSFET driving LED string 5. If unused, leave G5 unconnected.
5	D5	D5	Drain sense input 5 Drain sense input for external MOSFET 5. Connect D5 through a $10M\Omega$ resistor to the drain of the external MOSFET driving LED string 5. If unused, connect D5 to ground.
6	S6	S6	Source sense input 6 Source sense input for external MOSFET 6. Connect S6 to the source of the external MOSFET and to the current sense resistor for LED string 6. The full-scale LED current threshold is reached when 500mV is across the current sense resistor. If unused, connect S6 to ground.
7	G6	G6	Gate output 6 Gate drive output for external MOSFET 6. Connect G6 to the gate of the external MOSFET driving LED string 6. If unused, leave G6 unconnected.
8	D6	D6	Drain sense input 6 Drain sense input for external MOSFET 6. Connect D6 through a $10M\Omega$ resistor to the drain of the external MOSFET driving LED string 6. If unused, connect D6 to ground.
9	S7	S7	Source sense input 7 Source sense input for external MOSFET 7. Connect S7 to the source of the external MOSFET and to the current sense resistor for LED string 7. The full-scale LED current threshold is reached when 500mV is across the current sense resistor. If unused, connect S7 to ground.
10	G7	G7	Gate output 7 Gate drive output for external MOSFET 7. Connect G7 to the gate of the external MOSFET driving LED string 7. If unused, leave G7 unconnected.

	PIN NAME				
PIN	MSL2161	MSL2160	PIN DESCRIPTION		
11	D7	D7	Drain sense input 7 Drain sense input for external MOSFET 7. Connect D7 through a $10M\Omega$ resistor to the drain of the external MOSFET driving LED string 7. If unused, connect D7 to ground.		
12	NC	MISO	MSL2161: No connect Make no connection to NC. MSL2160: Master input slave output		
			MISO is the SPI serial data output.		
13	SDA	MOSI	MSL2161: I²C serial data I/O SDA is the data I/O for the I²C serial interface.		
			MSL2160: Master output slave input MOSI is the SPI serial data input.		
14	SCL	SCK	MSL2161: I ² C serial clock input SCL is the clock input for the I ² C serial interface.		
14	JOL	SOR	MSL2160: SPI serial shift clock SCK is the clock input for the SPI bus.		
15	15 GND CSB		MSL2161: Ground Connect GND to system ground and to EP with short, wide traces.		
10			MSL2160: Chip select bar CSB is the chip select input for SPI transactions. CSB is active low.		
16	FLTB	FLTB	Fault indication output (active low) Open drain output FLTB sinks current to GND whenever a fault is detected and verified. FLTB remains low until the fault registers are read, and reasserts if the fault persists.		
17	ADDR	ADDR	Slave ID selection inputs Connect ADDR to GND through a resistor to set the device address for the serial interface.		
18	FBO3	FBO3	Efficiency Optimizer output 3 Connect FBO3 to the third power supply's feedback node. Connect FBO3 to GND if unused.		
19	FBO2	FBO2	Efficiency Optimizer output 2 Connect FBO2 to the second power supply's feedback node. Connect FBO2 to GND if unused.		
20	FBO1	FBO1	Efficiency Optimizer output 1 Connect FBO1 to the first power supply's feedback node. Connect FBO1 to GND if unused.		
21	\$8	S8	Source sense input 8 Source sense input for external MOSFET 8. Connect S8 to the source of the external MOSFET and to the current sense resistor for LED string 8. The full-scale LED current threshold is reached when 500mV is across the current sense resistor. If unused, connect S8 to ground.		
22	G8	G8	Gate output 8 Gate drive output for external MOSFET 8. Connect G8 to the gate of the external MOSFET driving LED string 8. If unused, leave G8 unconnected.		
23	D8	D8	Drain sense input 8 Drain sense input for external MOSFET 8. Connect D8 through a $10M\Omega$ resistor to the drain of the external MOSFET driving LED string 8. If unused, connect D8 to ground.		



Table 3. Pin Assignments

	PIN NAME		
PIN	MSL2161	MSL2160	PIN DESCRIPTION
24	S9	S9	Source sense input 9 Source sense input for external MOSFET 9. Connect S9 to the source of the external MOSFET and to the current sense resistor for LED string 9. The full-scale LED current threshold is reached when 500mV is across the current sense resistor. If unused, connect S9 to ground.
25	G9	G9	Gate output 9 Gate drive output for external MOSFET 9. Connect G9 to the gate of the external MOSFET driving LED string 9. If unused, leave G9 unconnected.
26	D9	D9	Drain sense input 9 Drain sense input for external MOSFET 9. Connect D9 through a $10M\Omega$ resistor to the drain of the external MOSFET driving LED string 9. If unused, connect D9 to ground.
27	S10	S10	Source sense input 10 Source sense input for external MOSFET 10. Connect S10 to the source of the external MOSFET and to the current sense resistor for LED string 10. The full-scale LED current threshold is reached when 500mV is across the current sense resistor. If unused, connect S10 to ground.
28	G10	G10	Gate output 10 Gate drive output for external MOSFET 10. Connect G10 to the gate of the external MOSFET driving LED string 10. If unused, leave G10 unconnected.
29	D10	D10	Drain sense input 10 Drain sense input for external MOSFET 10. Connect D10 through a $10M\Omega$ resistor to the drain of the external MOSFET driving LED string 10. If unused, connect D10 to ground.
30	S11	S11	Source sense input 11 Source sense input for external MOSFET 11. Connect S11 to the source of the external MOSFET and to the current sense resistor for LED string 11. The full-scale LED current threshold is reached when 500mV is across the current sense resistor. If unused, connect S11 to ground.
31	G11	G11	Gate output 11 Gate drive output for external MOSFET 11. Connect G11 to the gate of the external MOSFET driving LED string 11. If unused, leave G11 unconnected.
32	D11	D11	Drain sense input 11 Drain sense input for external MOSFET 11. Connect D11 through a $10M\Omega$ resistor to the drain of the external MOSFET driving LED string 11. If unused, connect D11 to ground.
33	S12	S12	Source sense input 12 Source sense input for external MOSFET 12. Connect S12 to the source of the external MOSFET and to the current sense resistor for LED string 12. The full-scale LED current threshold is reached when 500mV is across the current sense resistor. If unused, connect S12 to ground.
34	G12	G12	Gate output 12 Gate drive output for external MOSFET 12. Connect G12 to the gate of the external MOSFET driving LED string 12. If unused, leave G12 unconnected.

	PIN NAME		DIVI DEGODIDEION			
PIN	MSL2161	MSL2160	PIN DESCRIPTION			
35	D12	D12	Drain sense input 12 Drain sense input for external MOSFET 12. Connect D12 through a $10M\Omega$ resistor to the drain of the external MOSFET driving LED string 12. If unused, connect D12 to ground.			
36	S13	S13	Source sense input 13 Source sense input for external MOSFET 13. Connect S13 to the source of the external MOSFET and to the current sense resistor for LED string 13. The full-scale LED current threshold is reached when 500mV is across the current sense resistor. If unused, connect S13 to ground.			
37	G13	G13	Gate output 13 Gate drive output for external MOSFET 13. Connect G13 to the gate of the external MOSFET driving LED string 13. If unused, leave G13 unconnected.			
38	D13	D13	Drain sense input 13 Drain sense input for external MOSFET 13. Connect D13 through a $10M\Omega$ resistor to the drain of the external MOSFET driving LED string 13. If unused, connect D13 to ground.			
39	S14	S14	Source sense input 14 Source sense input for external MOSFET 14. Connect S14 to the source of the external MOSFET and to the current sense resistor for LED string 14. The full-scale LED current threshold is reached when 500mV is across the current sense resistor. If unused, connect S14 to ground.			
40	G14	G14	Gate output 14 Gate drive output for external MOSFET 14. Connect G14 to the gate of the external MOSFET driving LED string 14. If unused, leave G14 unconnected.			
41	D14	D14	Drain sense input 14 Drain sense input for external MOSFET 14. Connect D14 through a $10M\Omega$ resistor to the drain of the external MOSFET driving LED string 14. If unused, connect D14 to ground.			
42	S15	S15	Source sense input 15 Source sense input for external MOSFET 15. Connect S15 to the source of the external MOSFET and to the current sense resistor for LED string 15. The full-scale LED current threshold is reached when 500mV is across the current sense resistor. If unused, connect S15 to ground.			
43	G15	G15	Gate output 15 Gate drive output for external MOSFET 15. Connect G15 to the gate of the external MOSFET driving LED string 15. If unused, leave G15 unconnected.			
44	D15	D15	Drain sense input 15 Drain sense input for external MOSFET 15. Connect D15 through a $10M\Omega$ resistor to the drain of the external MOSFET driving LED string 15. If unused, connect D15 to ground.			
45	VCC	VCC	5V internal LDO regulator output VCC powers the FBO outputs. Bypass VCC to GND with a 4.7µF ceramic capacitor placed close to VCC.			



Table 3. Pin Assignments

	PIN NAME		
PIN	MSL2161	MSL2160	PIN DESCRIPTION
46	PHI	PHI	Phase synchronization input Drive PHI with an external signal from 40Hz to 10kHz to synchronize the MSL2160/1 clock. PHI is typically driven with the VSYNC signal.
47	GSC	GSC	Gate shift clock input Drive GSC with the gate shift clock of the video signal, from to MHz. GSC is typically driven with the HSYNC signal.
48	PWM	PWM	PWM input PWM allows external control of the brightness of all LED strings. Drive PWM with a pulse-width modulated signal with duty cycle ranging from 0% to 100% and frequency up to 5kHz. When not configured as an input, PWM is high impedance.
49	EN	EN	Enable input (active high) Drive EN high to turn on the MSL2160/1, drive EN low to turn off the MSL2160/1. For automatic start up, connect EN to VIN. When EN is low the entire device, including the serial interface, is turned off. Driving EN high initiates a boot load of the EEPROM data into the control registers, simulating a cold start up.
50	VIN	VIN	Supply voltage input Connect a 12V ±10% supply to VIN. Bypass VIN to GND with a 10µF ceramic capacitor placed close to VIN.
51	VDD	VDD	2.5V internal LDO regulator output VDD powers internal logic. Bypass VDD to GND with a 4.7µF ceramic capacitor placed close to VDD.
52	S0	S0	Source sense input 0 Source sense input for external MOSFET 0. Connect S0 to the source of the external MOSFET and to the current sense resistor for LED string 0. The full-scale LED current threshold is reached when 500mV is across the current sense resistor. If unused, connect S0 to ground.
53	G0	G0	Gate output 0 Gate drive output for external MOSFET 0. Connect G0 to the gate of the external MOSFET driving LED string 0. If unused, leave G0 unconnected.
54	D0	D0	Drain sense input 0 Drain sense input for external MOSFET 0. Connect D0 through a $10M\Omega$ resistor to the drain of the external MOSFET driving LED string 0. If unused, connect D0 to ground.
55	S1	S1	Source sense input 1 Source sense input for external MOSFET 1. Connect S1 to the source of the external MOSFET and to the current sense resistor for LED string 1. The full-scale LED current threshold is reached when 500mV is across the current sense resistor. If unused, connect S1 to ground.
56	G1	G1	Gate output 1 Gate drive output for external MOSFET 1. Connect G1 to the gate of the external MOSFET driving LED string 1. If unused, leave G1 unconnected.

DIN	PIN N	IAME	DIN DECODIDE ON
PIN	MSL2161	MSL2160	PIN DESCRIPTION
57	D1	D1	Drain sense input 1 Drain sense input for external MOSFET 1. Connect D1 through a $10M\Omega$ resistor to the drain of the external MOSFET driving LED string 1. If unused, connect D1 to ground.
58	S2	S2	Source sense input 2 Source sense input for external MOSFET 2. Connect S2 to the source of the external MOSFET and to the current sense resistor for LED string 2. The full-scale LED current threshold is reached when 500mV is across the current sense resistor. If unused, connect S2 to ground.
59	G2	G2	Gate output 2 Gate drive output for external MOSFET 2. Connect G2 to the gate of the external MOSFET driving LED string 2. If unused, leave G2 unconnected.
60	D2	D2	Drain sense input 2 Drain sense input for external MOSFET 2. Connect D2 through a $10M\Omega$ resistor to the drain of the external MOSFET driving LED string 2. If unused, connect D2 to ground.
61	S3	S3	Source sense input 3 Source sense input for external MOSFET 3. Connect S3 to the source of the external MOSFET and to the current sense resistor for LED string 3. The full-scale LED current threshold is reached when 500mV is across the current sense resistor. If unused, connect S3 to ground.
62	G3	G3	Gate output 3 Gate drive output for external MOSFET 3. Connect G3 to the gate of the external MOSFET driving LED string 3. If unused, leave G3 unconnected.
63	D3	D3	Drain sense input 3 Drain sense input for external MOSFET 3. Connect D3 through a $10M\Omega$ resistor to the drain of the external MOSFET driving LED string 3. If unused, connect D3 to ground.
64	S4	S4	Source sense input 4 Source sense input for external MOSFET 4. Connect S4 to the source of the external MOSFET and to the current sense resistor for LED string 4. The full-scale LED current threshold is reached when 500mV is across the current sense resistor. If unused, connect S4 to ground.
EP	EP	EP	Exposed pad, power ground EP is the thermal relief pad for the device. Connect EP to system ground and GND using short, wide traces.



Absolute Maximum Ratings

Voltage (With Respect to GND)

VIN, EN, D0 - D15	-0.3V to +16V
G0 - G15	0.3V to (VIN + 0.3V)
VDD	0.3V to +2.75V
ADDR, S0 - S15	0.3V to (VDD + 0.3V)
FLTB, SDA, SCL, SCK	0.3V to +5.5V
FBO1, FBO2, FBO3, PHI, GSC, PWM, MOSI, MISO, CSB	0.3V to (VCC + 0.3V)
VCC	0.3V to +6V
EP	0.3V to +0.3V
Current (Into Pin)	
VIN	500mA
FBO1, FBO2, FBO3	+0µA to -800µA
G0 - G15	±100mA
All other pins	±20mA
Continuous Power Dissipation	
64-Pin 9mm x 9mm QFN (derate 38mW/°C above $T_A = +70$ °C)	2100mW
Ambient Operating Temperature Range $T_A = T_{MIN}$ to T_{MAX}	-40°C to +105°C
Junction Temperature	+125°C
Storage Temperature Range	-65°C to +125°C
Lead Soldering Temperature, 10s	+300°C

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Electrical Characteristics

Typical Application Circuit, $V_{VIN} = 12V$, $T_A = T_{MIN}$ to $T_{MAX'}$ unless otherwise noted. Typical values are $T_A = +25$ °C

PARAMETER	SYMBOL	CONDITIONS AND NOTES	MIN	TYP	MAX	UNIT	
DC ELECTRICAL CHARACTERISTICS							
VIN Operating Supply Voltage			10.8	12	13.2	V	
VINI On cratics County Council		All LED strings on 50% duty cycle		15	30	1	
VIN Operating Supply Current		All LED strings on 100% duty cycle		30	70	mA	
VIN Shutdown Supply Current		EN = GND		500		μA	
VIN Sleep Supply Current		SLEEP = 1, SDA, SCL, ADDR, PWM, PHI and GSC at GND or VDD		2.75		mA	
VCC Regulation Voltage			4.5	5.0	5.5	V	
VDD Regulation Voltage			2.4	2.5	2.6	V	
EN Input High Voltage			1.8			V	
EN Input Low Voltage					0.9	V	
PWM, PHI, GSC, Input High Voltage			0.7 x V _{VDD}			V	
PWM, PHI, GSC, Input Low Voltage					0.3 x V _{VDD}	V	
PHI, GSC Output High Voltage		I _{SOURCE} = 5mA	V _{VDD} - 0.4				
PHI, GSC, FLTB Output Low Voltage		I _{SINK} = 6mA			0.4	V	
FBO1 - FBO3 Feedback Output Current		FBOn DAC = 0xFF, V _{FBOn} = 0	208	306	360	μA	
FBO1 - FBO3 Feedback Output Current Step		INCRSTEP[0:1] = 00, DECRSTEP[0:1] = 00		1.2		μA	
D0 - D15 Short Circuit Fault Detection Threshold				8		V	
G0 - G15 Open Circuit Fault Detection Threshold				8		V	
G0 - G15 Maximum Gate Drive Current			0.7			mA	
G0 - G15 Maximum Gate Drive Voltage			V _{VIN} - 2.5			V	
S0 - S15 Regulation Voltage		ISTR = 0xFF	475	500	525	mV	
CO C1E Voltago Appuração		ISTR = 0x7F, T _A = +25°C	-1.5		+1.5	01	
S0 - S15 Voltage Accuracy		ISTR = 0x7F	-4		+4	%	
S0 - S15 Regulation Voltage Matching		ISTR = 0x7F, T _A = +25°C, 1 st string to all others	-0.5		+0.5	0/	
50 - 515 Regulation voltage iviationing		ISTR = 0x7F, string to average of all strings	-1.5		+1.5	%	
Thermal Shutdown Temperature		Temperature rising, hysteresis = 15°C (Note 1)		135		°C	



PARAMETER	SYMBOL	CONDITIONS AND NOTES	MIN	TYP	MAX	UNIT
SPI LOGIC LEVELS, MSL2160						
MOSI, SCK, CSB Input High Voltage			0.7 x V _{VDD}			V
MOSI, SCK, CSB Input Low Voltage					0.3 x V _{VDD}	V
MISO Output High Voltage		I _{SOURCE} = 5mA	V _{VCC} - 0.4			V
MISO Output Low Voltage		I _{SINK} = 6mA			0.4	V

PARAMETER	SYMBOL	CONDITIONS AND NOTES	MIN	TYP	MAX	UNIT
I ² C LOGIC LEVELS, MSL2161						
SDA, SCL Input High Voltage			0.7 x V _{VDD}			V
SDA, SCL Input Low Voltage					0.3 x V _{VDD}	V
SDA Output Low Voltage		I _{SINK} = 6mA			0.4	V

PARAMETER	CONDITIONS AND NOTES	MIN	TYP	MAX	UNIT	
AC ELECTRICAL CHARACTERISTICS						
Internal Oscillator Frequency	f _{osc}	OSCFREQ = 0x04, T _A = 25°C	19.4	20	20.6	MHz
PHI Frequency	f _{PHI}		0.04		10	kHz
GSC Frequency		GSCMUL = 0, GSCDIV = 0 (Note 9)	f _{PHI}		2.5	MHz
DWW Fraguency		EXTALTEN = 0 (Note 1)			5	kHz
PWM Frequency		EXTALTEN = 1 (Note 1)			1	KUZ
PWM Duty Cycle		(Note 1, Note 9)	0		100	%

PARAMETER	SYMBOL	CONDITIONS AND NOTES	MIN	TYP	MAX	UNIT				
SPI TIMING CHARACTERISTICS, MSL2160										
SCK Frequency					20	MHz				
CSB to Rising Edge of SCK Setup Time	t _{CSB:SCK(SU)}		20			ns				
Rising Edge of SCK to CSB Hold Time	t _{CSB:SCK(HD)}		20			ns				
MOSI to Rising Edge of SCK Setup Time	t _{MOSI(SU)}		20			ns				
Rising Edge of SCK to MOSI Hold Time	t _{MOSI(HD)}		20			ns				
CSB Falling Edge to MISO Data Valid	t _{CSB:MISO(DV)}				50	ns				
CSB Rising Edge to MISO High Impedance	t _{CSB:MISO(HIZ)}	(Note 1)			50	ns				

PARAMETER	SYMBOL	CONDITIONS AND NOTES	MIN	TYP	MAX	UNIT
SCK Falling Edge to MISO Data Valid	t _{valid}	(Note 1)			20	ns
SCK High Time			20			ns
SCK Low Time			20			ns
MOSI, CSB, SCK Signal Rise Time	t _{R(SPI)}	Receiving (Note 6)		5.0		ns
MOSI, CSB, SCK Signal Fall Time	t _{F(SPI)}	Receiving (Note 6)		5.0		ns
MISO Signal Rise Time		C _{load} = 10pF (Note 6)		20		ns
MISO Signal Fall Time		C _{load} = 10pF (Note 6)		20		ns

PARAMETER	SYMBOL	CONDITIONS AND NOTES	MIN	TYP	MAX	UNIT
I ² C TIMING CHARACTERISTICS, MSL2161						
SCL Clock Frequency	1/t _{scl}	I2CTOEN = 0 (Note 2)	0		1	MHz
Bus Timeout Period	4	f _{osc} = 20MHz, T _A = 25°C	29	30	31	ms
Bus Timeout Period	timeout	f _{osc} = 16MHz to 23MHz	60	00,000 / f _c	SC	S
STOP to START Condition Bus Free Time	t _{BUF}		0.5			μs
Repeated START condition Hold Time	t _{HD:STA}		0.26			μs
Repeated START condition Setup Time	t _{su:sta}		0.26			μs
STOP Condition Setup Time	t _{su:stop}		0.26			μs
SDA Data Hold Time	t _{HD:DAT}		0			ns
SDA Data Valid Acknowledge Time	t _{VD:ACK}	(Note 3)	0.05		0.45	μs
SDA Data Valid Time	t _{VD:DAT}	(Note 4)	0.05		0.45	μs
SDA Data Set-Up Time	t _{su:DAT}		100			ns
SCL Clock Low Period	t _{LOW}		0.5			μs
SCL Clock High Period	t _{HIGH}		0.26			μs
SDA, SCL Fall Time	t _f	(Note 1, Note 5, Note 6)			120	ns
SDA, SCL Rise Time	t _r				120	ns
SDA, SCL Input Suppression Filter Period	t _{sp}	(Note 2, Note 7)		50		ns

- Note 1. Guaranteed by design, not production tested.
- Note 2. Minimum SCL clock frequency is limited by the bus timeout feature, which resets the serial bus interface if either SDA or SCL is held low for time-out. Disable bus timeout via the Fault Enable register 0x03[D6].
- Note 3. $t_{\text{VD:ACK}}$ = SCL LOW to SDA (out) LOW acknowledge time.
- Note 4. $t_{VD:DAT}$ = minimum SDA output data-valid time following SCL LOW transition.
- Note 5. A master device must internally provide an SDA hold time of at least 300ns to ensure an SCL low state.
- Note 6. The maximum SDA, SCL and MOSI rise times are 300ns. This allows series protection resistors to be connected between these inputs and the bus lines without exceeding the maximum allowable rise time. The maximum SDA and MISO fall time is 250ns.
- Note 7. The MSL2161 includes input filters on SDA, SCL and ADDR inputs that suppress noise less than 50ns.
- Note 8. The GSC input frequency multiplied by (GSCMUL + 1) should not exceed 2.5MHz.
- Note 9. When PWMDIRECT = 1 and PHDLYEN = 1 (external PWM with auto phase shift enabled), PWM duty cycles at 0% and 100% are guaranteed, other duty cycles require minimum on or off time of one full internal oscillator clock cycle and frequency greater than $(f_{OSC}/10^6)$ Hz.



Typical Application Circuit

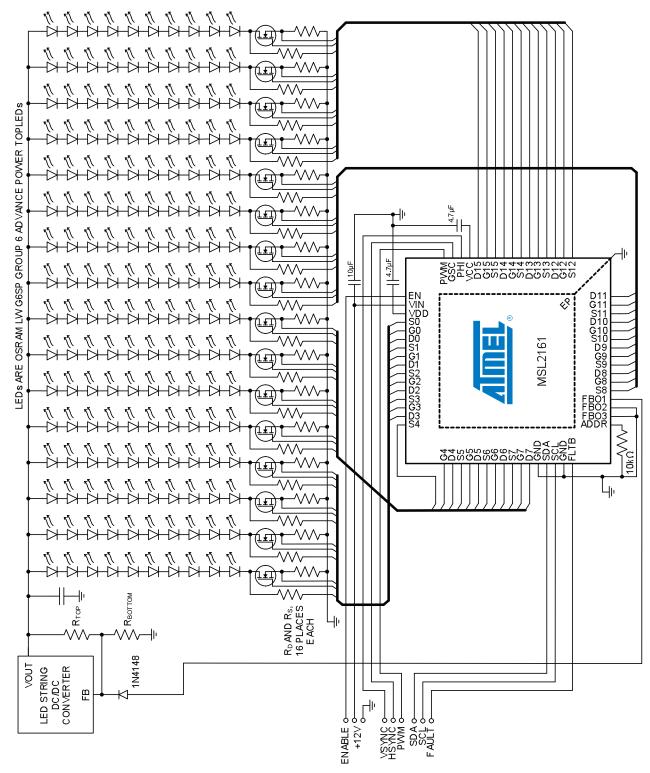


Figure 4. Atmel LED Driver-MSL2161 Driving 160 White LEDs in 16 Strings

16-string, White and RGB LED Drivers with Adaptive Configuration, EEPROM, and SPI/I²C/SMBus Serial Interface

Detailed Description

The MSL2160 and MSL2161 are highly integrated, flexible, multi-string LED drivers that use external MOSFETs to allow high LED string currents, and include power supply control to maximize efficiency. The drivers optionally connect to a video subsystem to offer a simple architecture for use in LCD TV backlight applications. Up to eight devices can be cascaded together to drive large numbers of LED strings in a system. The drivers provide multiple methods of controlling LED brightness through both peak current control and pulse width control of the string drive signals. Peak current control offers excellent color consistency, while pulse width control allows brightness management. An on-chip EEPROM holds all the default control register values. At power-up, the data in the EEPROM are automatically copied directly to the control registers, setting up the device for operation. The factory programmed EEPROM values can be changed through the serial interface if a different powerup condition is desired.

The devices interface to an MCU via I²C (MSL2161) or SPI (MSL2160). The robust 1MHz I²C interface supports up to eight devices on the bus. The 20MHz, bus-addressable SPI bus supports up to eight devices per chip select line. While typically the LED drive PWM signal is internally generated, both drivers also accept an external direct PWM drive signal applied to the PWM input that sets the PWM duty and the frequency of the LEDs drive signal. Both devices also feature phase spreading when external PWM direct drive is used. With phase spreading enabled, a progressive 1/16 phase delay per string helps reduce both the transient load on the LED power supplies and the power supply input capacitor size requirements.

The PWM frequency of the drivers is either synchronized to an external signal applied to PHI, generated from the internal oscillator for standalone applications, or set directly by a signal at the PWM input. Typically the VSYNC signal from the video system is used for the PHI input. A frequency multiplier (1x to 32x) processes this signal for use by the PWM engine. The on time of each string is individually programmed via the device registers, providing a peak resolution of 12 bits when using the onchip PWM generator. The actual resolution of the PWM frequency depends on the ratio of the GSC frequency (typically provided by a systems HSYNC signal, but can be internally generated) to the PHI frequency because the on time of a string is programmed as a 12-bit count of the number of GSC clock cycles. This count can be further scaled by an 8-bit global intensity value, when enabled. The GSC clock is also used to precisely set each string's phase delay so that it is synchronized to its physical position relative to the video frame.

The Efficiency Optimizers control a wide range of different external DC-DC and AC-DC converter architectures. Multiple drivers in a system communicate in real time among themselves to select an optimized operating voltage for the LEDs. This allows design of the power supply for the worst case forward voltage (V_f) of the LEDs without concern about excessive power dissipation issues. During the start-up sequence, the MSL2160/1 automatically reduces the power supply voltage to the minimum voltage required to keep the LEDs in current regulation. The devices can be configured to periodically perform this optimization to compensate for changes in LED forward voltage, and to assure continued optimum power savings.



Internal Regulators and Enable Input

The MSL2160/1 includes two internal linear regulators that provide VCC (5V) and VDD (2.5V) for internal circuitry. VIN (12V nominal) supplies the VCC and VDD regulators. Bypass VIN to GND with a $10\mu F$ capacitor close to the device. Bypass VCC to GND with a $4.7\mu F$ capacitor close to the device.

The MSL2160/1 enables input, EN, enables the device. Drive EN low to enter low power operation, which lowers quiescent current draw to less than 20µA. With EN low, the serial interface is ignored, the Efficiency Optimizer is disabled, and all strings are turned off. Drive EN high to turn on the device. When EN is driven high, the contents of the EEPROM are boot loaded into the control registers, simulating a cold start up, and all bits in the fault registers are cleared to 0.

Setting the Maximum LED String Current with a Source Resistor

The maximum string current, $I_{LEDn'}$ for each string is set by a shunt resistor connected to ground from the source terminal of the string drive MOSFET. The feedback threshold is 500mV. Determine the resistor value using:

$$R_{\rm S} = \frac{0.5}{I_{\rm LED}}$$
 , where $\rm ~I_{\rm LED}$ is in amperes and $\rm R_{\rm S}$ is in ohms.

For example, a full-scale LED current of 100mA returns $R_s = 5\Omega$. The current for all LED strings is reduced from the full-scale value with 8-bit resolution using ISTR, the string current control register 0x31.

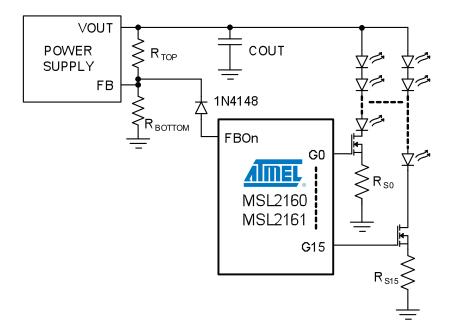


Figure 5. FBOn Connects to the Power Supply Voltage Divider Through a Diode.

16-string, White and RGB LED Drivers with Adaptive Configuration, EEPROM, and SPI/I²C/SMBus Serial Interface

Connecting the Efficiency Optimizer to an LED String Power Supply and Selecting Resistors

The MSL2160/1 are designed to control external LED string power supplies that use voltage dividers (R_{TOP} and R_{BOTTOM} in Figure 5) to set the output voltage, and whose regulation feedback voltage is not more than 3.5V. The Efficiency Optimizer improves power efficiency by injecting a current of between 0 and 255 μ A into the voltage dividers of the external power supplies, dynamically adjusting their outputs to the minimum voltage required by the LED strings. To select the resistors, first determine $V_{OUT(MIN)}$ and $V_{OUT(MIN)}$ and $V_{OUT(MIN)}$ and maximum string supply voltage limits, using:

$$V_{OUT(MIN)} = (V_{f(MIN)} * [\#ofLEDs]) + 0.5$$
 and

$$V_{OUT(MAX)} = (V_{f(MAX)} * [\#ofLEDs]) + 0.5$$

where $V_{f(MIN)}$ and $V_{f(MAX)}$ are the LED minimum and maximum forward voltage drops at the peak current set by R_S (page 12). For example, if the LED data are $V_{f(MIN)}=3.5 V$ and $V_{f(MAX)}=3.8 V$, and ten LEDs are used in a string, then the total minimum and maximum voltage drops across a string are 35V and 38V, respectively. Adding an allowance of 0.5V for the string drive MOSFET headroom brings $V_{OUT(MIN)}$ to 35.5V and $V_{OUT(MAX)}$ to 38.5V. Then, determine R_{TOP} using:

$$R_{\mathit{TOP}} = \frac{V_{\mathit{OUT}(\mathit{MAX})} - V_{\mathit{OUT}(\mathit{MIN})}}{I_{\mathit{FBOn}(\mathit{MAX})}}$$

 $where \ I_{FBOn(MAX)} \ is \ the \ 255 \mu A \ maximum \ output \ current \ of \ the \ efficiency \ optimizer \ outputs \ FBOn. \ Finally, \ determine \ R_{BOTTOM} \ using: \ in the \ efficiency \ optimizer \ outputs \ FBOn. \ Finally, \ determine \ R_{BOTTOM} \ using: \ in the \ efficiency \ optimizer \ outputs \ optimizer \ optimizer \ outputs \ optimizer \ optimizer \ optimizer \ optimizer \ outputs \ optimizer \ optimizer \ optimizer \ outputs \ optimizer \ optimizer \ outputs \ optimizer \ op$

$$R_{\scriptscriptstyle BOTTOM} = R_{\scriptscriptstyle TOP} * \frac{V_{\scriptscriptstyle FB}}{V_{\scriptscriptstyle OUT(MAX)} - V_{\scriptscriptstyle FB}},$$

where V_{FB} is the regulation feedback voltage of the power supply. Place a diode (1N4148 or similar) between FBOn and the supply's feedback node to protect the MSL2160/1 against current flow into FBOn. Assign all strings powered by a common supply to the proper FBO output using string set registers 0x40 - 0x5F.

Once configured, determine the change in power supply output voltage in response to a change in FBO output current using:

$$\Delta V_{OUT} = \Delta I_{FBO} * R_{TOP}$$

Direct PWM Control of the LED Strings

An external PWM signal applied to the PWM input allows direct PWM control over the strings when bits PWMEN and PWMDIRECT (bits D0 and D1 in PWM control register 0x2D) are set to 1. This configuration bypasses PHI and GSC, but allows LED string phase delay via the phase delay enable bit, PHADLYEN (bit D0 of register 0x2E). With phase delay enabled, a progressive delay of 1/16 the PWM frame is calculated and applied successively to each string drive signal.

The PWM input can also be configured as a gate for the output of the PWM engine using PWM global enable (bit D2 of the PWM control register 0x2D).



Register Map and the EEPROM

Register Map Summary

Control the MSL2160/1 using the registers in the range 0x00 - 0xBF (Table 4). Two additional registers, 0xC0 and 0xC1, allow access to, and programming of, the EEPROM. The power-up default values for all control registers are stored within the on-chip EEPROM, and any of these EEPROM values may be changed through the serial interface.

Table 4. Atmel LED Drivers-MSL2160/1 Register Map

AD	DRESS AND					REC	SISTER DATA						
	SISTER NAME	FUNCTION	D7	D6	D5	D4	D3	D2	D1	D0			
0x00	STRINGEN0	LED string	STR7EN	STR6EN	STR5EN	STR4EN	STR3EN	STR2EN	STR1EN	STR0EN			
0x01	STRINGEN1	enables	STR15EN	STR14EN	STR13EN	STR12EN	STR11EN	STR10EN	STR9EN	STR8EN			
0x02	CONFIG	Configuration	SLEEP	-	-	-	FLDBKEN		STRSCDLY[2:0]]			
0x03	FLTEN	Fault enable	-	-	I ² CTOEN	PHIMAXFEN	GSCMAXFEN	STRSCFEN	STROCFEN	FBOOCFEN			
0x04	FLTMASK0	String fault	FEN7	FEN6	FEN5	FEN4	FEN3	FEN2	FEN1	FEN0			
0x05	FLTMASK1	mask	FEN15	FEN14	FEN13	FEN12	FEN11	FEN10	FEN9	FEN8			
0x06	FLTSTATUS*	Fault status	FLTBDRV	-	-	PHIMAXFLT	GSCMAXFLT	STRSCFLT	STROCFLT	FBOOCFLT			
0x07	OCSTAT0*	String open	OC7	OC6	OC5	OC4	OC3	OC2	OC1	OC0			
0x08	OCSTAT1*	circuit fault status	OC15	OC14	OC13	OC12	OC11	OC10	OC9	OC8			
0x09	SCSTAT0*	String short	SC7	SC6	SC5	SC4	SC3	SC2	SC1	SC0			
0x0A	SCSTAT1*	circuit fault status	SC15	SC14	SC13	SC12	SC11	SC10	SC9	SC8			
	0x0B - 0x0	E					UNUSED						
0x0F	OSCFREQ	Oscillator frequency	-	-	-	-	-		OSCFREQ[2:0]				
0x10	FBOCTRL0	Efficiency	HDRMS ⁻	TEP[1:0]	RECA	LDLY[1:0]	SETTL	E[1:0]	IERRCO	DNF[1:0]			
0x11	FBOCTRL1	optimizer	INCRST	EP[1:0]	DECR	STEP[1:0] INITPWM ACAL10		ACAL100	ACALEN	ICHKDIS			
0x12	FBOCTRL2	control	-	-	-	-	FBO3OCEN	FBO2OCEN	FBO10CEN	FBOEN			
0x13	FBODAC1*	Efficiency				FB	ODAC1[7:0]						
0x14	FBODAC2*	optimizer DAC				FB	ODAC2[7:0]						
0x15	FBODAC3*	readback				FB	ODAC3[7:0]						
0x16	FBOSTATUS*	Efficiency optimizer status	FBO3OC	FBO2OC	FBO1OC	FBO3ACT	FBO2ACT	FBO1ACT	FBOCAL	FBOINITCAL			
	0x17- 0x1I	F					UNUSED						
0x20	GSCCTRL	GSC processing control	GSCCHK- SEL	-	-	-	GSCMAXEN	GSCPOL	GSCPHI- SYNCEN	GSCINTEN			
0x21		Internal clock		'		GS	SSCCNTR[7:0]						
0x22	GSCCNTR	counter for GSC				GS	SCCNTR[15:8]						
0x23	GSCMUL	GSC multiplier	-	-	-			GSCMUL[4:0]					
0x24	GSCDIV	GSC divider				G	GSCDIV[7:0]						

ΔD	DRESS AND					REG	ISTER DATA			
	SISTER NAME	FUNCTION	D7	D6	D5	D4	D3	D2	D1	D0
0x25		Max oscillator				GS	SCMAX[7:0]			
0x26	GSCMAX	cycles between GSC pulses				GS	CMAX[15:8]			
0x27	PHICTRL	PHI processing control	PHICHK- SEL	-	-	-	-	PHIMAXEN	PHIPOL	PHIINTEN
0x28		Internal clock				PH	IICNTR[7:0]			
0x29	PHICNTR	counter for PHI				PH	ICNTR[15:8]			
0x2A	PHIMUL	PHI multiplier	-	-	-			PHIMUL[4:0]		
0x2B		Max GSC		,	'	Pl	HIMAX[7:0]			
0x2C	PHIMAX	cycles between PHI pulses				PH	IIMAX[15:8]			
0x2D	PWMCTRL0	514/14	GINT+1EN	GINTEN	ALTEN	OVRFLOZEN	OVRFLOEN	PWM- GLBLEN	PWMDIRECT	PWMEN
0x2E	PWMCTRL1	PWM control	-	-	-	-	EXTALTEN	PHOVR- FLOZEN	PHOVR- FLOEN	PHADLYEN
0x2F	GINT	Global PWM scaling					GINT[7:0]			
0x30	ALTGINT	Alternate global PWM scaling				AL	TGINT[7:0]			
0x31	ISTR	8-bit global string current scaling					STR[7:0]			
0x32	PWMSTATUS*	PWM and counter status	PHIM	IAXERRCNT	[2:0]	PHIMAX1FLT	PHISIGFLT	GSCSIGFLT	PHICNTRFLT	GINT- MULERR
0x33	PHIPCNTR*	PHI pulse counter and status	PHICNTR- MAX	-	-		į	PHIPCNTR[4:0]	
0x34	GSCPCNTR*	GSC pulse				GSCPI	JLSECNTR[7:0]			
0x35	GSCPCIVIK	counter	-	-	-		GSC	:PULSECNTR[12:8]	
C)x36 - 0x3F					1	JNUSED			
0x40		Phase delay				PI	HDLY0[7:0]			
0x41	STR0SET	and EO assignment for string 0	FBOSE	T0[1:0]	-	-		PHDL	.Y[11:8]	
\downarrow										
0x5E		Phase delay				PH	IDLY15[7:0]			
0x5F	STR15SET	and EO assignment for string 15	FBOSET	Γ15[1:0]	-	-		PHDL	.Y[11:8]	
0x60	D)A/A40	PWM setting				F	PWM0[7:0]			
0x61	PWM0	for string 0	-	-	-	-		PWI	M0[11:8]	



AD	DRESS AND					REG	ISTER DATA							
	SISTER NAME	FUNCTION	D7	D6	D5	D4	D3	D2	D1	D0				
\														
0x7E	PWM15	PWM setting				P\	VM15[7:0]							
0x7F	1 771713	for string 14	-	-	-	-		PWM	15[11:8]					
0x80		Alternate				ALTI	PHDLY0[7:0]							
0x81	ALTSTR0SET	phase delay for string 0	-	-	-	-	ALTPHDLY[11:8]							
\							↓							
0x9E		Alternate				ALTP	PHDLY15[7:0]							
0x9F	ALTSTR15SET	phase delay for string 15	-	-	-	-		ALTPHE	DLY[11:8]					
0xA0		Alternate				ALT	PWM0[7:0]							
0xA1	ALTPWM0	PWM setting for string 0	-	-	-	-		ALTPV	VM0[11:8]					
\														
0xBE		Alternate				ALT	PWM15[7:0]							
0xBF	ALTPWM15	PWM setting for string 15	-	-	-	-	ALTPWM15[11:8]							
0xC0	E2ADDR	EEPROM	-				E2ADDR[6:0]							
0xC1	E2CTRLSTA	read/write access	E2BUSY	BLDACT	E2ERR	-	-		RWCTRL[2:0]					

^{*} Read-only registers

16-string, White and RGB LED Drivers with Adaptive Configuration, EEPROM, and SPI/I²C/SMBus Serial Interface

Register Power-up Defaults

Register power-up default values are shown in Table 5.

Table 5. Atmel LED Drivers-MSL2160/1 Register Power-up Defaults

REG	SISTER NAME	POWER-UP CONDITION				REG	SISTE	R DA	TA		
	D ADDRESS	REGISTERS INITIALIZED FROM EEPROM	D7	D6	D5	D4	D3	D2	D1	D0	HEX
0x00	STRINGEN0		1	1	1	1	1	1	1	1	FF
0x01	STRINGEN1	All LED string drive outputs enabled		1	1	1	1	1	1	1	FF
0x02	CONFIG	String short circuit confirmation delay = 256µs String current fold-back enabled Device is not asleep	0	0	0	0	1	1	0	1	0D
0x03	FLTEN	FBO open circuit fault detect globally enabled String open circuit fault detect globally enabled LED short circuit fault detect globally enabled GSC max fault detect globally disabled PHI max fault detect globally disabled I2C timeout enabled		0	1	0	0	1	1	1	27
0x04	FLTMASK0			1	1	1	1	1	1	1	FF
0x05	FLTMASK1	Fault detection individually enabled for all strings	1	1	1	1	1	1	1	1	FF
0x0F	OSCFREQ	f _{osc} = 20MHz	0	0	0	0	0	1	0	0	04
0x10	FBOCTRL0	Current sink error confirmation delay = 2µs FBO power supply settling time allowance = 4ms		1	0	0	1	0	0	1	49
0x11	FBOCTRL1	Efficiency Optimizer auto-recalibration delay = 1s Efficiency Optimizer headroom steps = 3 MOSFET current sink error detection enabled	0	0	0	1	1	0	1	0	1A
0x12	FBOCTRL2	Efficiency Optimizer auto-recalibration enabled PWM settings used during auto-recalibration PWM settings used during initial calibration Efficiency Optimizer correction step size = 1 LSB (1μA) Efficiency Optimizer initial calibration step size = 1 LSB (1μA) FBO outputs globally enabled Open circuit detection enabled for all three FBO outputs	0	0	0	0	1	1	1	1	0F
0x20	GSCCTRL	External signal at GSC is selected for input to the PWM engine GSC not internally synchronized to PHI PWM drive synchronized to falling edge of external GSC GSC maximum count fault detect is disabled Although disabled, GSC max fault monitors \mathbf{f}_{pGSC}	0	0	0	0	0	0	0	0	00
0x21	GSCCNTR	Although disabled, internal GSC frequency	0	1	0	1	0	0	0	0	50
0x22	GOOGNIK	f _{GGEN} = 20MHz / (80 + 1) = 246kHz	0	0	0	0	0	0	0	0	00
0x23	GSCMUL	GSC multiplexer output is multiplied by 4 (register setting + 1)	0	0	0	0	0	0	1	1	03
0x24	GSCDIV	GSC multiplier output is divided by 1 (register setting + 1)	0	0	0	0	0	0	0	0	00
0x25	GSCMAX	Although disabled GSC may count is set to 174 clock cycles	1	0	1	0	1	1	1	0	AE
0x26	GSCMAX Although disabled, GSC max count is set to 174 clock cycl		0	0	0	0	0	0	0	0	00



Table 5. Atmel LED Drivers-MSL2160/1 Register Power-up Defaults

REG	ISTER NAME	POWER-UP CONDITION				REC	SISTE	R DA	ГА		
	DADDRESS	REGISTERS INITIALIZED FROM EEPROM	D7	D6	D5	D4	D3	D2	D1	D0	HEX
0x27	PHICTRL	External signal at PHI selected for input to PWM engine PWM engine is synchronized to the falling edge of PHI PHI maximum count fault detect is disabled Although disabled, PHI max count monitors f _{pPHI}	0	0	0	0	0	0	0	0	00
0x28	PHICNTR	Although disabled, internal PHI frequency	1	0	1	1	0	0	0	0	В0
0x29		f _{PGEN} = 20MHz / (8 * (10416 + 1)) = 240Hz	0	0	1	0	1	0	0	0	28
0x2A	PHIMUL	PHI multiplier = 1 (register setting + 1)	0	0	0	0	0	0	0	0	00
0x2B	PHIMAX	Although disabled, PHI maximum count = 4148	0	0	1	1	0	1	0	0	34
0x2C			0	0	0	1	0	0	0	0	10
0x2D	PWMCTRL0	PWM operation enabled Individual LED string drive pulse widths internally determined PWM input does not gate the output of the PWM engine String on times allowed to extend beyond end of PWM frame String on times allowed to extend into frame zero	1	0	0	1	1	0	0	1	99
0x2E	PWMCTRL1	Alternate timing not used Global intensity (GINT) disabled Although disabled, (GINT + 1) is provided to the PWM engine String drive phasing enabled Delayed string turn on beginning after PWM frame allowed Delayed turn on occurring in frame zero allowed Alternate timing not selected by PWM input state	0	0	0	0	0	1	1	1	07
0x2F	GINT	Although disabled, global intensity set to (127 + 1) / 256 = 50% (1 added in numerator because bit D7 of 0x2D = 1)	0	1	1	1	1	1	1	1	7F
0x30	ALTGINT	Although disabled, alternate global intensity set to (95 + 1) / 256 = 37.5% (1 added in numerator because bit D7 of 0x2D = 1)	0	1	0	1	1	1	1	1	5F
0x31	ISTR	Strings current scaled to 50% of R _{Sn} setting	0	1	1	1	1	1	1	1	7F
0x40	STR0SET	All strings set to zero phase delay	0	0	0	0	0	0	0	0	00
0x41	STRUSET	Strings assigned as follows:	0	1	0	0	0	0	0	0	40
\downarrow	\downarrow	FBO1: All strings					\				
0x5E	STR15SET	FBO2: None FBO3: None	0		0	0	0	0	0	0	0 00
0x5F			0	-	1	0	0	0	0	0	0 40
0x60	PWM0		0	_	0	0	0	0	0	0	0 00 02
0x61	↓	All strings have PWM t = 512 GSC avalor	0		0	U	0	U	0	1	0 02
↓ 0x7E	↓	All strings have PWM t _{on} = 512 GSC cycles			0	0	0	0	0	0	0 00
0x7E	PWM15		0	-	0	0	0	0	0	1	0 02

REG	SISTER NAME	POWER-UP CONDITION				RE	GISTE	R DA	λTΑ			
AN	D ADDRESS	REGISTERS INITIALIZED FROM EEPROM	D7	D6	D5	D4	D3	D2	D1	D0	н	EX
0x80	ALTSTR0SET		0		0	0	0	0	0	0	0	00
0x81	ALISTRUSET		0		0	0	0	0	0	0	0	40
\		All strings set to zero phase delay					1					
0x9E	ALTSTR15SET				0	0	0	0	0	0	0	00
0x9F	ALISTRIBSET		0		0	0	0	0	0	0	0	00
0xA0	ALTPWM0		0		0	0	0	0	0	0	0	00
0xA1	ALTEVNIO		0		0	0	0	0	0	1	0	02
\downarrow	\downarrow	All strings set with alternate PWM t_{ON} = 512 GSC cycles					1	,				
0xBE	ALTPWM15		0		0	0	0	0	0	0	0	00
0xBF	ALIFWINIS		0		0	0	0	0	0	1	0	02
	REGISTERS WITH FIXED INITIAL VALUES											
0xC0	E2ADDR	EEPROM 7 bit address = 0x00	0		0	0	0	0	0	0	0	00
0xC1	E2CTRLSTA	EEPROM read/write disabled	0		0	0	0	0	0	0	0	00

^{*} Read-only registers



Atmel Corporation

2325 Orchard Parkway San Jose, CA 95131 USA

Tel: (+1)(408) 441-0311 **Fax:** (+1)(408) 487-2600

www.atmel.com

Atmel Asia Limited

Unit 01-5 & 16, 19F BEA Tower, Millennium City 5 418 Kwun Tong Road Kwun Tong, Kowloon HONG KONG

Tel: (+852) 2245-6100 **Fax:** (+852) 2722-1369

Atmel Munich GmbH

Business Campus Parkring 4 D-85748 Garching b. Munich GERMANY

Tel: (+49) 89-31970-0 **Fax:** (+49) 89-3194621

Atmel Japan

9F, Tonetsu Shinkawa Bldg. 1-24-8 Shinkawa Chuo-ku, Tokyo 104-0033

Tel: (+81)(3) 3523-3551 **Fax:** (+81)(3) 3523-7581

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